OIPE COL

Substitute for form 1449A/PTO

Sheet

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

1

of

2

	Complete if Known
Application Number	10/716,250
Filing Date	November 17, 2003
First Named Inventor	Hai Deng
Art Unit	2818
Examiner Name	Dag Wrugen
Attorney Docket Number	12017681

			U.S. PATE	NT DOCUMENTS	
		Document Number	Publication Date		Pages, Columns, Lines, Where
Examiner Initials*	Cite No.'	Number - Kind Code ² (if known)	or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Relevant Passages or Relevant Figures Appear
the		US-2002/132468 A1	09-19-2002	Wong	
		US-			·
		US-			
		US-	7		
		US-			
		US-			
		US-			

	FOREIGN PATENT DOCUMENTS								
Examiner Cite No.'	Cite	Foreign Patent Document	O difference Date		Pages, Columns, Lines,	70			
	Country Code* - Number* - Kind Code* (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Where Relevant Passages or Relevant Figures Appear					
NO.0		DE 100 52 075 AT	05-02-2002	Bein et al.					
عهر	100	ded	.						
1	<u> </u>		1						
			1						
			Į į						
			Į.			<u> </u>			
			1						
			1						
			ì						

Examiner Signature	Voad	Date Considered	0167106

*Examiner. Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

'Applicant's unique citation designation number (optional). 'See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. 'Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). 'For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. 'Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. 'Applicant is to place a check mark here if English language Translation is attached.

Based on PTO/SB/08A (08-03) as modified by Blakely, Solokoff, Taylor & Zafman (wir) 08/11/2003.



Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

Sheet	2	of	2
	_		. –

Co	omplete if Known
Application Number	10/716,250
Filing Date	November 17, 2003
First Named Inventor	Hai Deng
Art Unit .	2818
Examiner Name	Das Nouceen
Attorney Docket Number	42P17681

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No.'	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²
lla		WANG, ZHENGBAO et al., "Pure-Silica Zeolite Low-k Dielectric Thin Films," Advanced Materials, Vol. 13, no. 10, May 17, 2001, pgs. 746-749.	
1.44	,		
		-	

		The state of the s	
Examiner Signature	Mag	Date Considered	
O.g. Later	1 secur	G11 17 0 h	

^{*}Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

^{&#}x27;Applicant's unique citation designation number. 'Applicant is to place a check mark here if English language Translation is attached.

Complete if Known Substitute for form 1449A/PTO Application Number 716,250 **INFORMATION DISCLOSURE** Filing Date First Named Inventor Hai Deng STATEMENT BY APPLICANT Art Unit 2818 (use as many sheets as necessary) **Examiner Name** Neugen of Attorney Docket Number | 42P17681 2 Sheet

							1.22.7700		
			Ú.	S. PATE	NT DO	CUMENTS			
Examiner Initials*	Cite No.¹	Document Number Number - Kind Code* (il known)	Public or iss	ation Date sue Date DD-YYYY		Name of Patent Applicant of Cited D		Pages, Columns, Lines, Whe Refevant Passages or Relevi Figures Appear	ere ant
Il Vin		US-6,573,131 B2	06-03	3-2003	Yan,	et al.			
2000		US-							
		US-							
		US-							
		US-							
		US-							
		US-							
		US-							
		US-							
		US-							
		US-				/			
		US-							
		US-					•		
		US-		\angle					
		US-			1				
		US-			7				
		US-			1				
		US-			1	<u> </u>			
		US-			ţ	ř			
		US-			1	7	·		
			FOF	REIGN	PATEN	IT DOCUMENTS	S		
	Cite	Foreign Patent Document			ļ	<u> </u>		Pages, Columns, Lines,	Τ.
Examiner Initials*	No.'	Country Code ¹ - Number ² - Kind Code ⁴ (ii	known)	Publicati MM-DD	on Date	", Name of	Patentee or Cited Document	Where Relevant Passages or Relevant Figures Appear	
					1			1	$oxed{oxed}$
					47.0				<u> </u>
					<u>t</u>				_
									ļ
 _									
						•			ļ
		. /							_
						-			
Examin	or T	-11				Date	1		-
Signatu		Meas				Considered	orli	7/06	

*Examiner: Initial if reference considered, whether or not cliation is in conformance with MPEP 609. Oraw line through cliation if not in conformance and not considered. Include copy of this form with next communication.

'Applicant's unique citation designation number (optional). 'See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. 'Enter Office that Issued the document, by the two-letter code (WIPO Standard ST.3). 'For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. 'Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. 'Applicant is to place a check mark here if English language Translation is attached.

Based on PTO/SB/08A (08-03) as modified by Blakely, Solokoff, Taylor & Zafman (wir) 08/11/2003.

Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Complete If Known		
			CLIDE	Application Number	10/716,250	
			SUNE	Filing Date	11/17/03	
			CANT	First Named Inventor	Hai Deng	
				Art Unit	28(8	
				Examiner Name	Das Names	
Sheet	2	of	2	Attorney Docket Number	42P17681	

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No.'	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T°
dhu		MORRIS, et al. METHOD OF FABRICATION OF LOW DIELECTRIC CONSTANT POROUS METAL SILICATE FILMS, U.S. Patent Application No. 10/323,988, Filed 12/17/2002, 23 pages.	T
dha		ZHENGBAO WANG, et al., Pure Silica Zeolite Films as Low-k Dielectrics by Spin-On of Nanoparticle Suspensions, Advanced Materials 2001, No. 19, October 2, pp.1463-1466	
dhe dhe dhe		ZHENGBAO WANG, et al., Silica Zeolite Low-k Dielectric Films, Department of Chemical and Environmental Engineering, University of California, Riverside, 15 pages.	

Examiner	71	Date	1 - 6	
Signature	(Das	Considered	01/17/06	

^{*}Examiner: Initial it reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

^{&#}x27;Applicant's unique citation designation number. 'Applicant is to place a check mark here if English language Translation is attached.